Features

- Low Input Voltage: 2.2V to 5.5V
- Enable/Disable and current regulation setting from ISNS pins.
- 24uA Supply Current
- 500nA Shutdown Current
- Ultra-Low On-State Resistance (Ron)
 Ron = 100mΩ at V_{IN} = 5.0V
- 2A Maximum Total Continuous Current
- Quick Output Discharge
- Reverse Current Blocking for both channels.
- Tiny 0.67mm x 1.02mm 6-pin WLP with 0.35mm pitch

Applications

- Wearables
- Smartphones
- Tablets
- Portable Device

General Description

YHM2511 is a dual output, ultra-small, low Ron and active low load switch. The device contains two N-channel MOSFETs that operate over an input voltage range of 2.2V to 5.5V. The switch is controlled by ISNS pin.

YHM2511 device limits the output current to a safe level by using a constant current mode when the output load exceeds the current regulation threshold. The current regulation threshold is adjusted by an external resistor added to ISNS pin. It has hard short protection for some abnormal situation at OUTx pins.

An internal reverse voltage comparator disables the power switch when the output voltage is driven higher than the input to protect devices on the input side of the switch when ISNS is logic low.

YHM2511 is available in a 6-bump, 0.35mm pitch, 0.67mm x1.02mm wafer-level package (WLP).



Figure 1. YHM2511 Internal Block Diagram

Internal Block diagram



Pin Configurations





YHM2511 WLP Pin Descriptions

WLP	Name	Description	
A1	OUT1	Output 1. Internal pull down to GND when switch off.	
B1 IN		Input and Power Supply. Bypass this input with 1µF or greater ceramic capacitor to ground.	
C1	OUT2	Output 2. Internal pull down to GND when switch off.	
A2	ISNS1	 Enable and current regulation setting for output 1. Connect external 0.1% resistor to set current regulation threshold. Pull high to disable the switch 1. Pull to GND to disable current regulation. 	
B2	GND	Ground.	
C2	ISNS2	 Enable and current regulation setting for output 2. Connect external 0.1% resistor to set current regulation threshold. Pull high to disable the switch 2. pull to GND to disable current regulation. 	



1 Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Disclaimer: YHMICROS reserves the right to make any change in circuit design, specification or other related things if needed without notice at any time.

Symbol	Parameters		Min.	Max.	Unit
Vin	IN to GND		-0.3	6	V
Vout	OUT1/2 to GND		-0.3	6	V
Visns	ISNS1/2 to GND	-0.3	6	V	
Іоит	Continuous Output Current for each output			1500	mA
lın	Continuous Input Current			2500	mA
Тѕтс	Storage Junction Temperature		-65	+150	°C
TJ	Operating Junction Temperature		7	+150	°C
T∟	Lead Temperature (Soldering, 10 Seconds)			+260	°C
All Pins	Electrostatic Discharge Capability	Human Body Model, EIA/JESD22-A114	5		KV
		Charged Device Model, JESD22-C101	2		

2 Recommend Operation Range

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance.

Parameters	Min.	Max.	Unit
Input Voltage: VIN	2.2	5.5	V
Peak Output Current: louт1/2		1.2	А
Ambient Temperature Range	-40	85	°C

3 Electrical Characteristics

Condition: $V_{IN} = 5V$, $T_A = -40^{\circ}C$ to +85°C. Typical values are at $T_A = +25^{\circ}C$, unless otherwise noted. (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Input Voltage Range	Vin		2.2		5.5	V
Quieseent Supply Current	l _{in}	Τ _A = 25°C, louτ= 0		24		μA
Quiescent Supply Current		-40°C ≤ T _A ≤ 85°C, louτ= 0			30	
Shutdown Current	ISHDN	VISNS = 1.2V, VOUT = 0		0.1	1.5	uA
IN UVLO Threshold	Vuvlo	VIN rising		1.9		V
IN UVLO Hysteresis	V _{UVLO_HYS}			100		mV
ISNS Logic High Threshold	Viн		0.92			V
ISNS Logic Low Threshold	Vil				0.4	V
Output Pull-Down Resistance	Rpd	V _{IN} = 1.8V, V _{ISNS} = 1.2V, I _{OUT} = 0			500	Ω
Output One Shot Pull-Down Time	tpd			20		ms



PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
On Resistance	Ron	V _{IN} = 5V, I _{OUT} = 200mA		100		mΩ
Current Regulation Accuracy	Acc	I _{LIMIT} = 275mA, Т _А = +25°С	-6		6	%
RCB Active Voltage	Vrcb	Vout - Vin		20		mV
RCB Activation Time	trcв			400		μs
Short Protection Response Time(Note 2)	tact			1		μs
Short Protection Active Time(Note 2)	tshort			20		μs
Short Protection Recover Time(Note 2)	trec			100		ms
Thermal Shutdown	Tshdn			150		°C
Thermal Hysteresis	T _{HYS}			20	•	°C
SWITCHING SPECIFICATIOI ($C_{Load} = 0.1 \mu F$, $R_{Load} = 10 \Omega$. T	NS ^T a = 25⁰C All	timing is 10% to 90% for rise time and 90%	5 to 10%	6 for fall	time).	
Turn On Delay Time	TDELAY	Time from VISNS < VIL to VOUT = $0.1 \times VIN$		500		μs
Soft Start Time (Rise Time)	tss			3		ms
Turn Off Delay Time	toff	Time from V _{ISNS} > V _{IH} to V _{OUT} = $0.9 \times V_{IN}$	~	40		μs
Fall Time	t FALL			10		μs

Note 1: All specifications are 100% production tested at TA = +25°C, unless otherwise noted. Specifications are over TA = -40°C to +85°C are guaranteed by design.

Note 2: Guaranteed by design; not production test.

4 **Description**

4.1 General Introduction

The YHM2511 is a dual output, ultra-small, low R_{ON} and active low load switch. The device contains two N-channel MOSFETs that operate over an input voltage range of 2.2V to 5.5V. The total input current is 2A, and each channel supports 1A continuous current at the same time.

4.2 Switch Enable Control

When VIN rise above 1.9V, the switch statuses are following below table. SW1 and SW2 are controlled independently. turns on after a delay time with soft start function. Turn off the switch would enable quick output discharge function, which means a discharge resistor is connected between OUT and GND.

Switch Name		SWn
ISNSn	>VIH	OFF
	<vı∟< th=""><th>ON</th></vı∟<>	ON

Table 1. Switch Control

Note1: N=1,2. SW is switch name. ISNS is pin name.





Figure 3. YHM2511 Power Up and Power Down Sequence

4.3 Over Current Protection and Current Monitor

4.3.1 Current Regulation Threshold calculation

The YHM2511 responds to over current condition by regulating output current to the I_{LIM} . Default I_{LIM} ($I_{DEFAULT}$) is adjustable by an external resistor which added to ISNS pin. When an over current condition is detected, the device maintains a constant output current and reduces the output voltage accordingly until thermal shutdown. The resistor can be calculated by:

$$R_{SNS}(\Omega) = 550800/I_{LIM}(mA) \tag{1}$$

YHM2511 can regulate the output current from 20mA to 1A by adding proper R_{SNS}. For example, if want to regulate output current to 50mA, choose R_{SNS} = 11.016K Ω . If want to regulate output current to 500mA, choose R_{SNS} = 1.1016K Ω .

4.4 Soft Start (SS)

YHM2511 integrated soft start function to avoid large inrush current during switches change from OFF to ON period. During this period, the current following through each switch is regulated in low level. Soft start time is about 500us after delay time from ISNS goes low. During this time, CC function is disabled. The inrush current may be become large after this time if the output capacitor is too large. The device may trigger CC condition.

4.5 Short Protection

YHM2511 has OUT1/2 short to GND protection. If the device detects the output current larger than I_{SHORT} when switch on, YHM2511 will regulate the corresponding switch current to a small one within a very short time (t_{ACT}) (typical: 1µs) and turn off switch after t_{SHORT} . (Typical: 20µs) This function is independent of current regulation. The device will try to close switch after t_{REC} (Typical 100ms) if the other conditions do not change. The SS period is added.

4.6 Reverse Current Protection

The reverse voltage protection turns off the N-channel MOSFET whenever the output voltage exceeds the input voltage by 20mV (TYP) for $400\mu s$ (TYP). This prevents damage to devices on the input side of the YHM2511. The YHM2511 device allows the N-channel MOSFET to turn on once the output voltage goes below the input voltage.

4.7 Thermal shutdown

When the part is in current regulation mode, to protect the chip from over temperature, the power path will be turned off when the junction temperature exceeds 150°C. The power path switch will be turned on and enter SS status again when temperature drop below 130°C. The device power dissipation capability is dependent on-board design and layout.

5 Application information

YHM2511 is designed to operate with an input range of 2.2V to 5.5V. The power supply must be well regulated and placed as close to the device terminal as possible. The power supply must be able to withstand all transient load current steps. In most situations, using an input capacitance (C_{IN}) of 1µF is sufficient to prevent the supply voltage from dipping when the switch is turned on. In cases where the power supply is slow to respond to a large transient current or large



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load current step, additional bulk capacitance may be required on the input. Placing a high-value electrolytic capacitor on the output pin is recommended when large transient currents are expected on the output.

5.1 1:2 Load Switch with Fixed CC Threshold

In this application, MCU two GPIOs connect to ISNSx Note1 pins with R_{SNSX} in series.



Figure 4. Typical Application 1: 1:2 Load Switch with Fixed CC Threshold

MCU pull down GPIO to GND to close SW1 or SW2 independently. Current regulation thresholds for each switch are set by R_{SNSX}^{Note1}. The threshold can be different for each channel. If the application does not need CC function, R_{SNSX}^{Note1} should be removed. MCU pull GPIO voltage higher than V_{IH} to open switches. Note1: X=1, 2.

6 Parameter Measurement Information





7 Typical Operating Characteristics



Figure 6 Switch Turn-on

Figure 7 Switch Turn-off



Figure 8 Single Channel RCB

Figure 9 Dual Channel (Short together) RCB





Figure 11 Shut Down Current





Figure 12 Switch 1 Rdson(VIN=5V)

Figure 13 Switch 2 Rdson(VIN=5V)



Figure 14 Switch 1 Rdson(VIN=3.6V)





Figure 15 Switch 2 Rdson(VIN=3.6V)



Figure 17 Switch 2 Rdson(VIN=2.5V)



8 Package Dimensions

WLCSP-6 0.67mmx1.02mm





9 Order Information

Part Number	Package	Top Mark (Note 1)	MOQ	
YHM2511W6T	6 WLCSP	XXXX	3000	

Note 1: The x letters are Lot id and production date information.

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Datasheet Change History

Rev	Date	Changes
1.0	Aug/2023	Initial Version

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